



Si2333DDS vs. Si2333CDS

Description: P-Channel, 12 V (D-S) MOSFET

Package: SOT-23

Pin Out: Identical

Part Number Replacements: Si2333DDS-T1-GE3 replaces Si2333CDS-T1-GE3
Si2333DDS-T1-GE3 replaces Si2333CDS-T1-E3

Table with 5 columns: PARAMETER, SYMBOL, Si2333DDS, Si2333CDS, UNIT. Rows include Drain-Source Voltage, Gate-Source Voltage, Continuous Drain Current, Pulsed Drain Current, etc.

Table with 9 columns: PARAMETER, SYMBOL, Si2333DDS (MIN., TYP., MAX.), Si2333CDS (MIN., TYP., MAX.), UNIT. Rows include Gate-Threshold Voltage, Gate-Body Leakage, Zero Gate Voltage Drain Current, etc.

- Note: NS designates not specified in original specification

Specification comparisons are supplied as a courtesy to compare two devices and do not constitute a commercial product datasheet or any guarantee of identical performance.